

## GENERAL DESCRIPTION

The LW57XX Series is an ultra-low noise, high PSRR LDO with enable function that operates from 1.9V to 5.5V. It provides up to 500mA output current.

The features of low noise and high PSRR make LW57XX ideal for noise-sensitive and analog applications.

The LW57XX Series integrate current limit, short circuit, thermal shut down, that protecting IC from being damaged.

Output voltage is selectable from 1.2V to 5.0V which fixed by laser trimming technologies, Step=50mV.

The LW57XX Series is available in SOT23-5L, DFN1x1-4L and DFN2x2-6L packages.

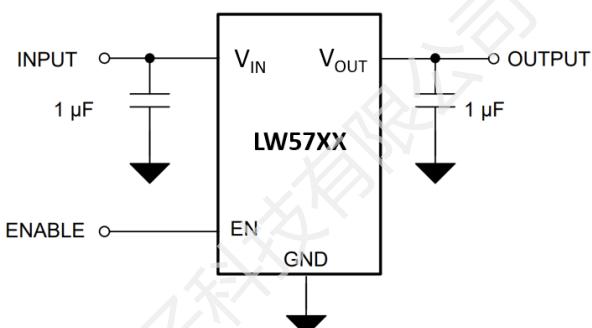
## FEATURES

- Ultra-Low Noise:  $5.29 \mu V_{RMS}$
- Output Accuracy:  $\pm 1\%$
- Low Quiescent Current: 10uA
- Low Dropout Voltage: 33mV@100mA/3.3V
- High PSRR: 90dB@1KHz,10mA
- Output Current: 500mA
- Excellent Line and Load Regulation
- Operating Voltage Range: from 1.9V to 5.5V
- Output Voltage Range: from 1.2V to 5.0V
- Over-Temperature Protection
- Current Limiting Protection
- Available in SOT23-5L, DFN1x1-4L and DFN2x2-6L Packages

## APPLICATIONS

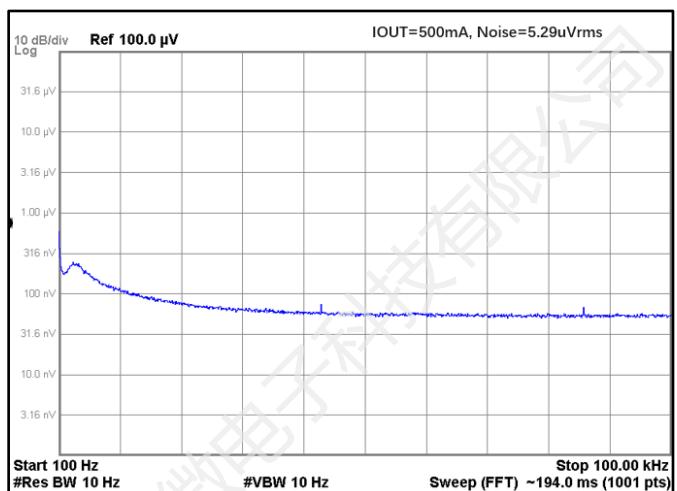
- Mobile Phones, Tablets, Digital Cameras
- Audio Devices
- RF Modules
- Clock Generator: VCO, PLL, etc.
- Noise-Sensitive Devices: ADC, DAC

## TYPICAL APPLICATION CIRCUIT



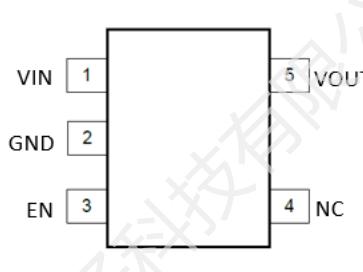
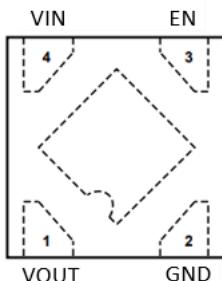
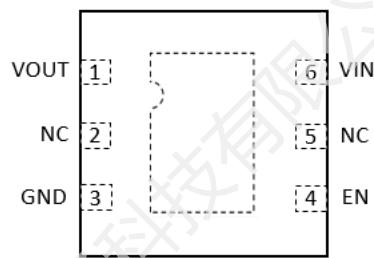
## TYPICAL PERFORMANCE

### CHARACTERISTICS



**PIN DESCRIPTION:**

PIN No			SYMBOL	DESCRIPTION
SOT23-5L	DFN1x1-4L	DFN2x2-6L		
1	4	6	VIN	Power Supply Input
2	2,E-PAD	3, E-PAD	GND	Ground
3	3	4	EN	Chip Enable
4	--	2,5	NC	Not Connected
5	1	1	VOUT	Output

**PIN ASSIGNMENT**

**SOT23-5L**

**DFN1x1-4L**

**DFN2x2-6L**
**MARK INFORMATION:**
**SOT23-5L**
**XX: VOLTAGE**
**YY: DATE CODE**
**LW57XX  
YYYYYY**
**DFN2x2-6L**
**XX: VOLTAGE**
**YY: DATE CODE**
**LW57XX  
YYYYYY**
**DFN1X1-4L**
**X: VOLTAGE**
**57X**
**.**

1.2V	1.5V	1.8V	2.5V	2.8V	3.0V	3.3V	3.6V	4.2V	5.0V
C	D	G	H	J	L	M	P	S	T



# LW57XX Series

Ultra-Low Noise, Fast-Start  
500mA LDO for RF and Analog Circuits

## ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>:

(TA = 25°C, unless otherwise specified.)

SYMBOL	ITEM	RATING	UNIT
V <sub>IN</sub>	Supply Voltage	-0.3~6.5	V
V <sub>EN</sub>	EN Pin Voltage	-0.3~6.5	V
V <sub>OUT</sub>	V <sub>OUT</sub> pin Voltage	-0.3~6.0	V
V <sub>(ESD)</sub>	ESD Susceptibility, HBM <sup>(2)</sup>	±4000	V
P <sub>D</sub>	Maximum Power Dissipation <sup>(3)</sup>	SOT23-5L	500
		DFN1x1-4L	415
		DFN2x2-6L	1600
PTR	Package Thermal Resistance Θ <sub>JA</sub> <sup>(3)</sup>	SOT23-5L	250
		DFN1x1-4L	301
		DFN2x2-6L	78
T <sub>J</sub>	Junction Temperature Range	-40~150	°C
T <sub>STG</sub>	Storage Temperature Range	-40~150	°C
T <sub>SOLDER</sub>	Lead Temperature (Soldering)	260 °C, 10s	

### Note:

1. Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability
2. per ANSI/ESDA/JEDEC JS-001
3. Device mounted on FR-4 PCB

## RECOMMENDED OPERATING RANGE:

SYMBOL	ITEM	VALUE	UNIT
V <sub>IN</sub>	V <sub>IN</sub> Supply Voltage	1.9~5.5	V
V <sub>EN</sub>	EN Pin Voltage	0~5.5	V
V <sub>OUT</sub>	V <sub>OUT</sub> Pin Voltage	1.2~5.0	V
I <sub>OUT</sub>	Output Current	0~500	mA
T <sub>J</sub>	Junction Temperature Range	-40~125	°C



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## ELECTRICAL CHARACTERISTICS:

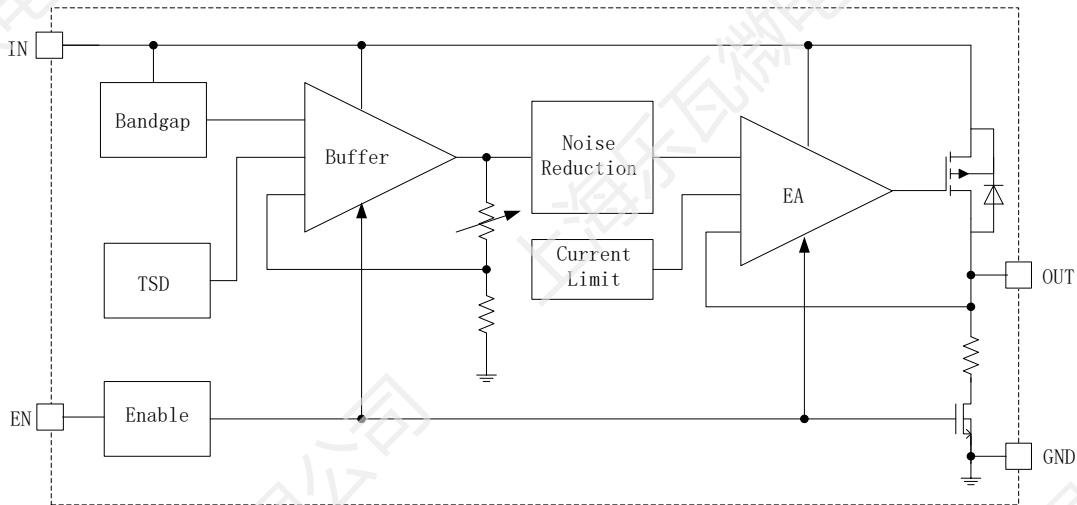
( $V_{IN}=V_{OUT}+1V$ ,  $V_{OUT}=1.8V$ ,  $C_{IN}=C_{OUT}=1\mu F$ ,  $T_A=25^{\circ}C$ , unless otherwise specified.)

Symbol	Parameter	Test Conditions	MIN	TYP	MAX	Units
$V_{IN}$	Input Voltage		1.9		5.5	V
$V_{OUT}$	Output Accuracy	$I_{OUT}=1mA$	-1.0		+1.0	%
$I_{LIM}$	Current Limit <sup>(1)</sup>	$V_{IN}=2.8V$ , $V_{OUT}=1.8V$	550	700		mA
		$V_{IN}=4.3V$ , $V_{OUT}=3.3V$	550	700		
$I_Q$	Quiescent Current	$V_{IN}=V_{EN}=V_{OUT}+1V$ , No Load		10	15	$\mu A$
$I_{SHD}$	Shutdown Current	$V_{IN}=5.5V$ , $V_{EN}=0V$			0.1	$\mu A$
$V_{DROP}$	Dropout Voltage <sup>(2)</sup>	$I_{OUT}=100mA$ , $V_{OUT}=1.8V$		60		mV
		$I_{OUT}=500mA$ , $V_{OUT}=1.8V$		300		
		$I_{OUT}=100mA$ , $V_{OUT}=3.3V$		33		
		$I_{OUT}=500mA$ , $V_{OUT}=3.3V$		170		
$S_{LINE}$	Line Regulation	$V_{IN}=V_{OUT}+1V$ to $5.5V$ , $I_{OUT}=1mA$		0.05	0.25	%/ $V$
$S_{LOAD}$	Load Regulation	$1mA \leq I_{OUT} \leq 500mA$		0.001	0.005	%/ $mA$
$I_{EN}$	EN Pull-Down Current	$V_{IN}=V_{EN}=5.5V$		0.15		$\mu A$
$V_{ENH}$	EN High Voltage	$V_{IN}=1.9V$ to $5.5V$ , $I_{OUT}=1mA$	1.5			V
$V_{ENL}$	EN Low Voltage				0.4	V
$PSRR$	Power Supply Rejection Ratio	$C_{IN}=\text{None}$ , $V_{OUT}=3.3V$ , $I_{OUT}=10mA$	$f=217Hz$	90		dB
			$f=1KHz$	90		
			$f=10KHz$	88		
			$f=100KHz$	60		
$e_N$	Output Noise Voltage	$V_{OUT}=3.3V$ , $BW=10Hz$ to $100kHz$	$I_{OUT}=1mA$	5.93		$\mu V_{RMS}$
			$I_{OUT}=500mA$	5.29		
$T_{SD}$	Overheat Protection	Temperature rising		160		$^{\circ}C$
$\Delta T_{SD}$	TSD Hysteresis	Temperature falling		20		$^{\circ}C$
$R_{DSCHG}$	Ron of $V_{OUT}$ Discharge MOSFET	$V_{IN}=5.5V$ , $V_{EN}=0V$		60		$\Omega$

## NOTES:

- Guaranteed by design
- The dropout voltage is defined as  $V_{IN} - V_{OUT}$ , when  $V_{OUT}=95\%*V_{OUT(NOM)}$

## SIMPLIFIED BLOCK DIAGRAM:



## DETAIL OPERATION DESCRIPTION:

The LW57XX is a low noise, high PSRR, low quiescent current, low drop-out voltage regulator. The input voltage range is from 1.9V to 5.5V, and the output current is up to 500mA.

### Error Amplifier

The Error Amplifier (EA) compares the internal reference voltage VREF with the output feedback voltage. Output of the error amplifier (EA) is used to control the gate voltage of P-MOSFET and ensures that the device provides good line and load regulation.

### Thermal Shutdown Protection

When the junction temperature exceeds 160°C(typ.), thermal shutdown is triggered and the device turns off. When the junction temperature falls below 140°C (typ.), the device turns on again.

### Current Limiting Protection

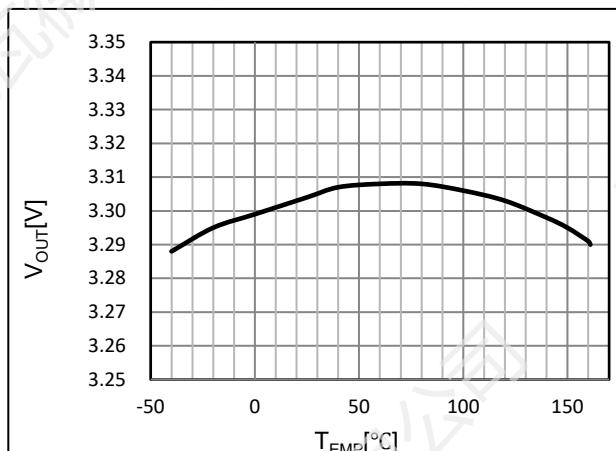
LW64XX provides current limiting function to prevent the device from damaging during overload. The output current is limited to 700mA (typ.).

**TYPICAL OPERATING CHARACTERISTICS:**

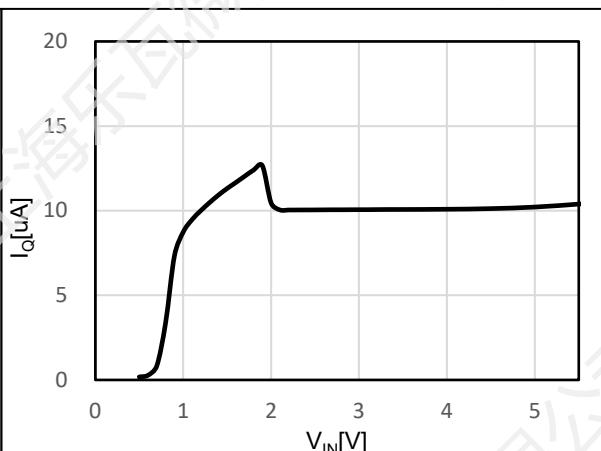
(Tested under  $T_J = 25^\circ\text{C}$ , unless otherwise specified)

**1. V<sub>OUT</sub> vs Temperature**

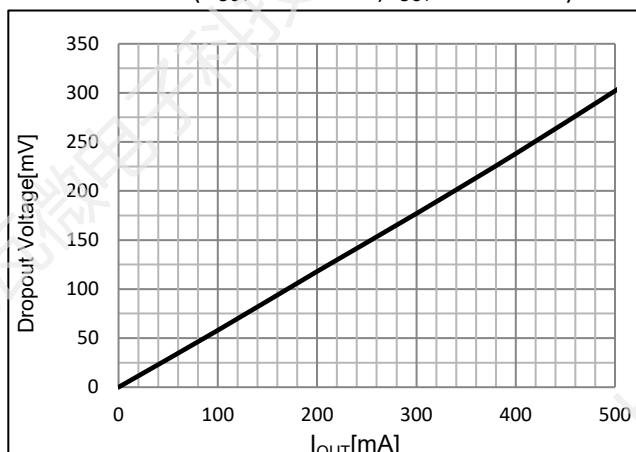
LW5733 ( $V_{IN} = 4.3\text{V}$ ,  $I_{OUT} = 10\text{mA}$ )


**2. I<sub>Q</sub> vs V<sub>IN</sub>**

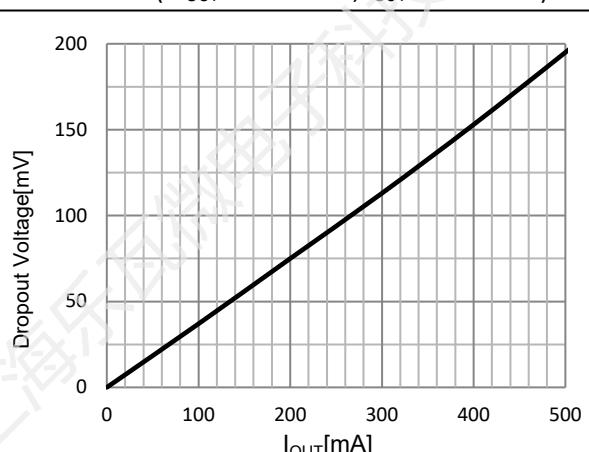
LW5718 ( $V_{IN} = 2.8\text{V}$ ,  $I_{OUT} = 0\text{mA}$ )


**3. Dropout Voltage vs I<sub>OUT</sub>**

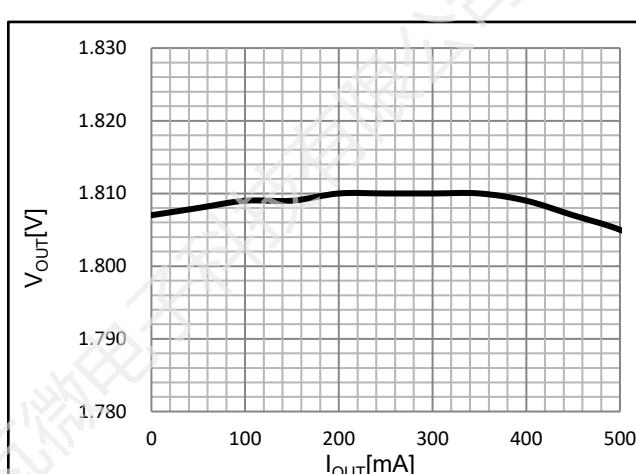
LW5718 ( $V_{OUT} = 95\% * 1.8\text{V}$ ,  $I_{OUT} = 0 \rightarrow 500\text{mA}$ )



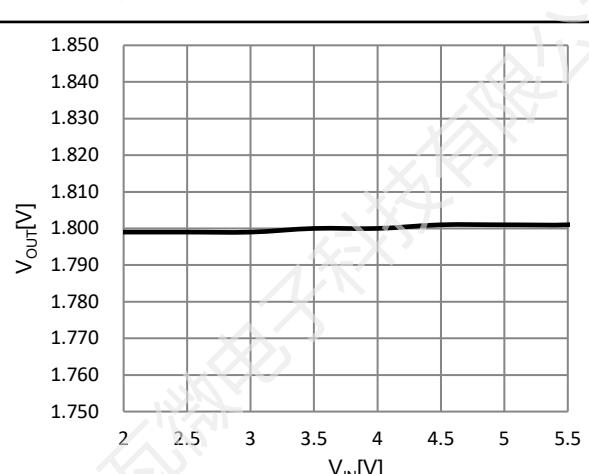
LW5730 ( $V_{OUT} = 95\% * 3.0\text{V}$ ,  $I_{OUT} = 0 \rightarrow 500\text{mA}$ )


**4. V<sub>OUT</sub> vs I<sub>OUT</sub>**

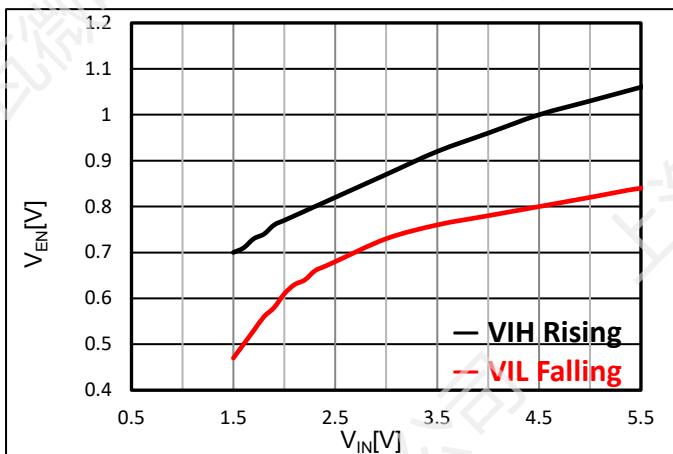
LW5718 ( $V_{IN} = 2.8\text{V}$ ,  $I_{OUT} = 1 \rightarrow 500\text{mA}$ )


**5. V<sub>OUT</sub> vs V<sub>IN</sub>**

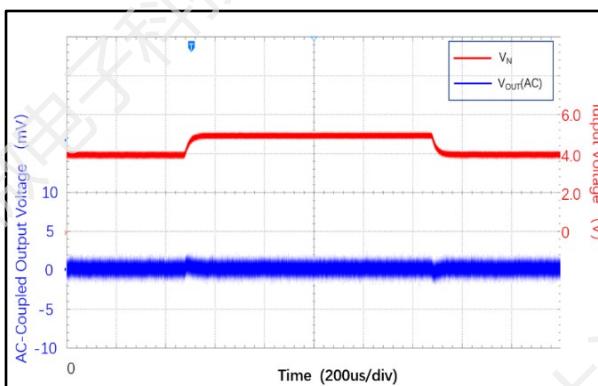
LW5718 ( $V_{IN} = 2.0\text{V} \rightarrow 5.5\text{V}$ ,  $V_{OUT} = 1.8\text{V}$ ,  $I_{OUT} = 1\text{mA}$ )



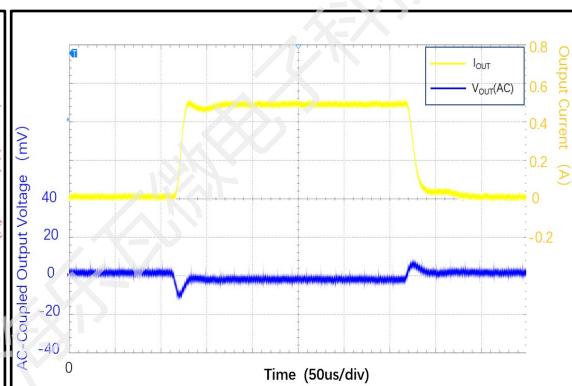
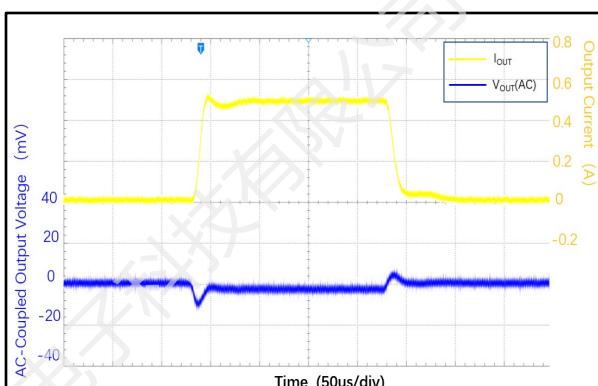
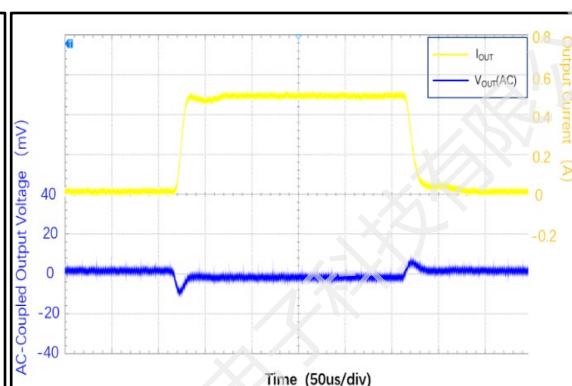
### 6. VEN Thresholds vs VIN

LW5718 ( $V_{IN}=2.8V$ ,  $I_{OUT}=0mA$ )


### 7. Line Transient

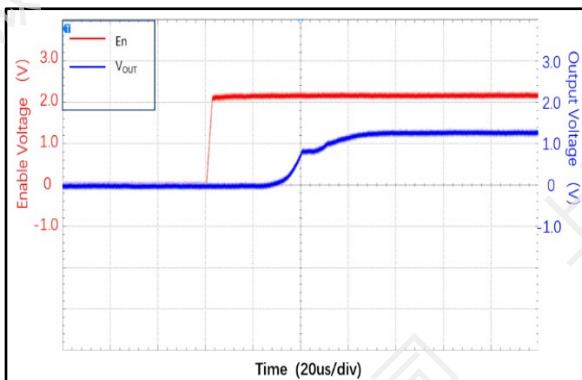
LW5730 ( $V_{IN}=4.0V \rightarrow 5.0V$ ,  $I_{OUT}=1mA$ )


### 8. Load Transient

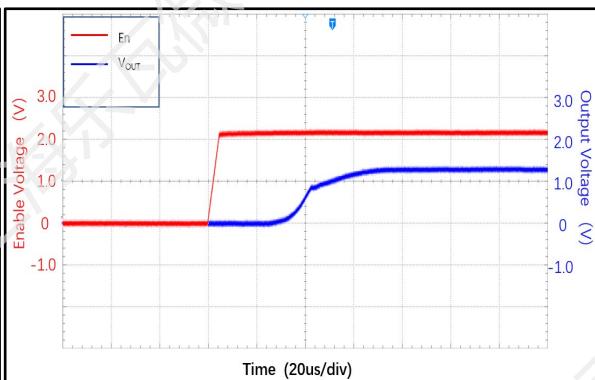
LW5712 ( $V_{IN}=2.2V$ ,  $I_{OUT}=1 \rightarrow 500mA$ )

LW5718 ( $V_{IN}=2.8V$ ,  $I_{OUT}=1 \rightarrow 500mA$ )

LW5730 ( $V_{IN}=4.0V$ ,  $I_{OUT}=1 \rightarrow 500mA$ )


### 9. Start-Up through EN

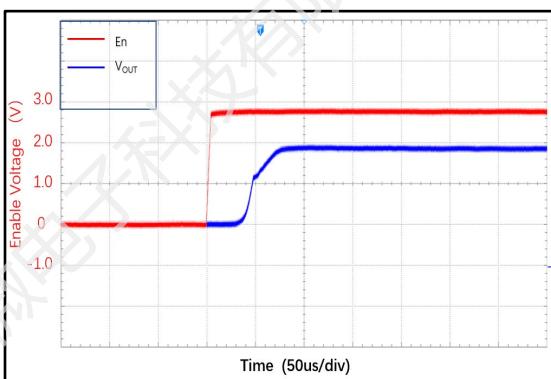
LW5712 ( $V_{EN}=0V \rightarrow 2.2V$ , No load)



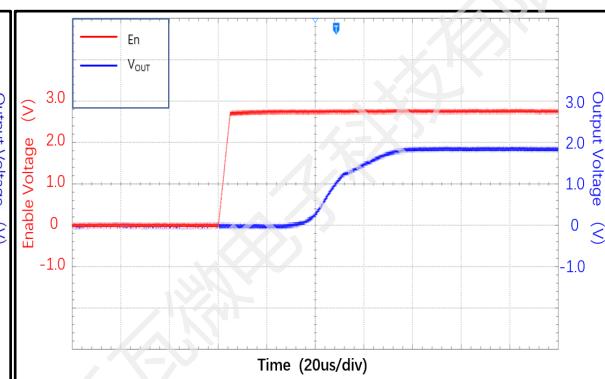
LW5712 ( $V_{EN}=0V \rightarrow 2.2V$ ,  $R_{OUT}=12\Omega$ )



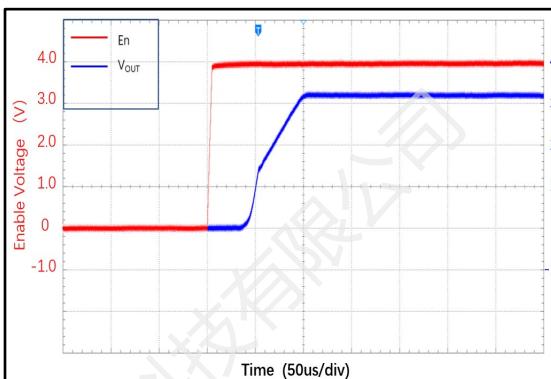
LW5718 ( $V_{EN}=0V \rightarrow 2.8V$ , No load)



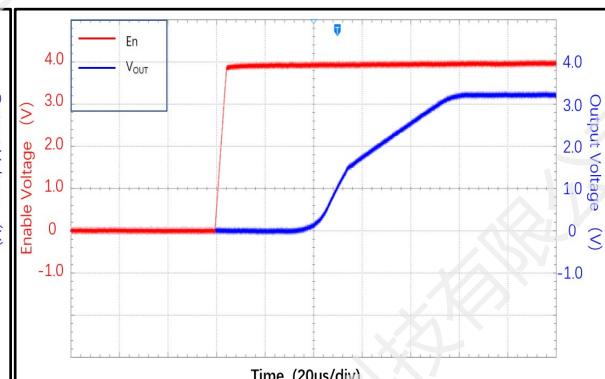
LW5718 ( $V_{EN}=0V \rightarrow 2.8V$ ,  $R_{OUT}=18\Omega$ )



LW5730 ( $V_{EN}=0V \rightarrow 4.0V$ , No load)

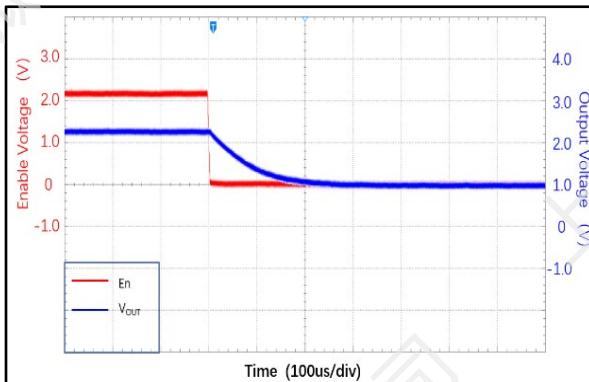


LW5730 ( $V_{EN}=0V \rightarrow 4.0V$ ,  $R_{OUT}=30\Omega$ )

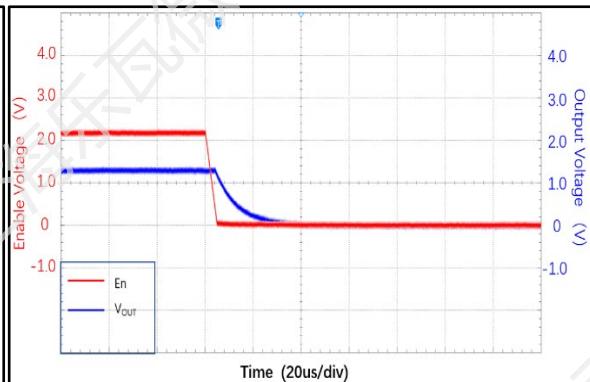


### 10. Shut-Down through EN

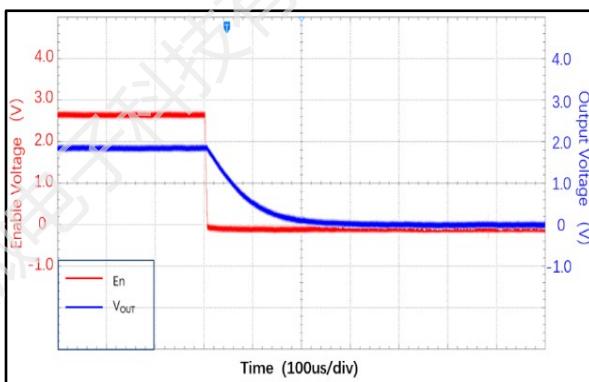
LW5712 ( $V_{EN}=2.2V \rightarrow 0V$ , No load)



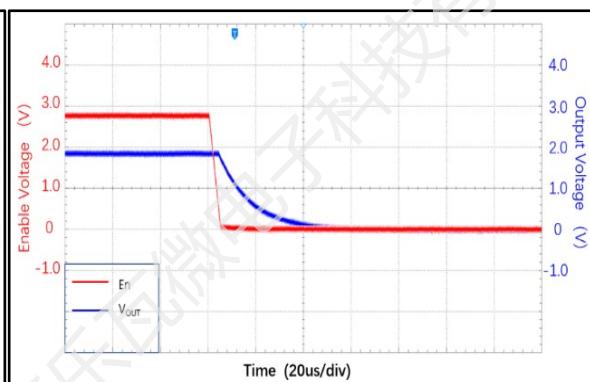
LW5712 ( $V_{EN}=2.2V \rightarrow 0V$ ,  $R_{OUT}=12\Omega$ )



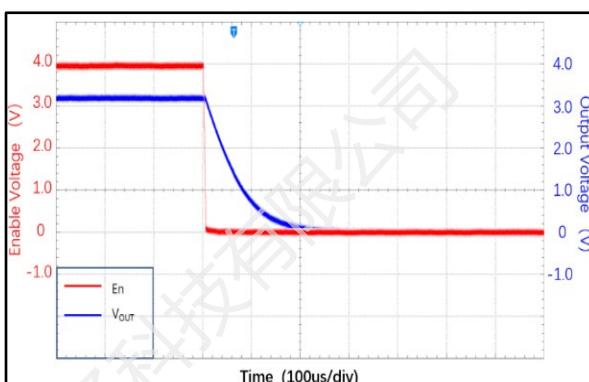
LW5718 ( $V_{EN}=2.8V \rightarrow 0V$ , No load)



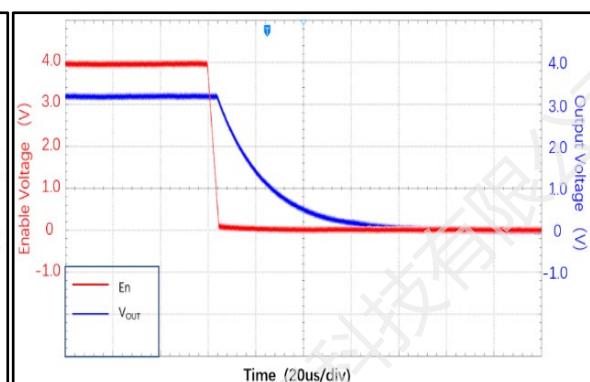
LW5718 ( $V_{EN}=2.8V \rightarrow 0V$ ,  $R_{OUT}=18\Omega$ )



LW5730 ( $V_{EN}=4.0V \rightarrow 0V$ , No load)

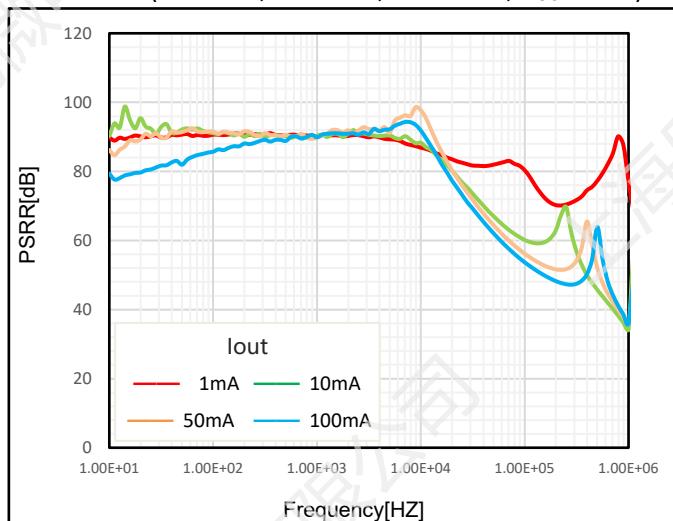


LW5730 ( $V_{EN}=4.0V \rightarrow 0V$ ,  $R_{OUT}=30\Omega$ )



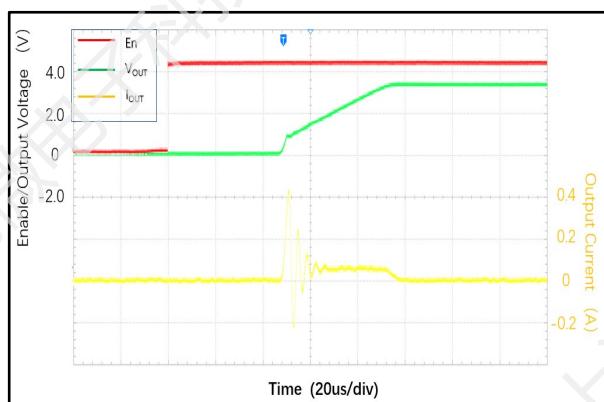
### 11. PSRR vs Frequency

LW5733 ( $V_{IN}=4.3V$ ,  $V_{PP}=0.5V$ ,  $C_{IN}=\text{none}$ ,  $C_{OUT}=1\mu F$ )

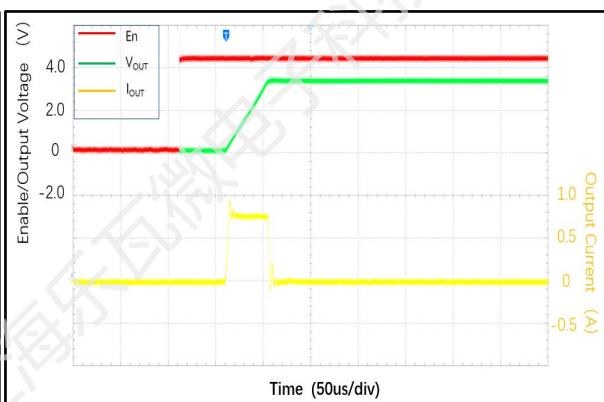


### 12. Inrush Current

LW5733 ( $V_{IN}=4.3V$ ,  $C_{OUT}=1\mu F$ , No load)

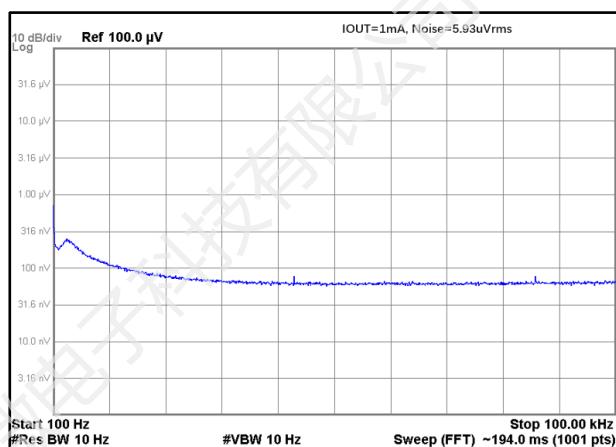


LW5733 ( $V_{IN}=4.3V$ ,  $C_{OUT}=10\mu F$ , No load)

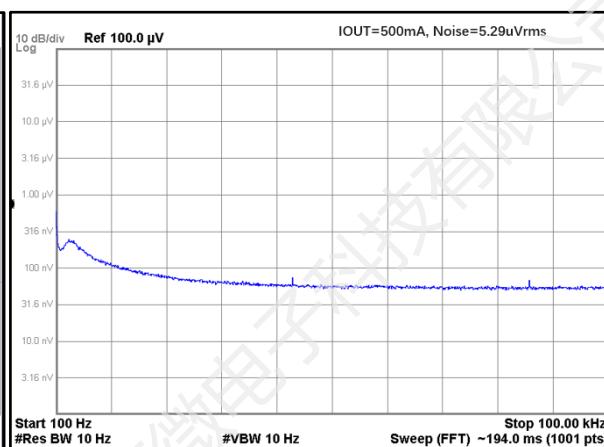


### 13. Output Noise Spectral Density vs Frequency

LW5733 ( $V_{IN}=4.3V$ ,  $C_{IN}=C_{OUT}=1\mu F$ ,  $I_{LOAD}=1mA$ )



LW5733 ( $V_{IN}=4.3V$ ,  $C_{IN}=C_{OUT}=1\mu F$ ,  $I_{LOAD}=500mA$ )





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500mA LDO for RF and Analog Circuits

## APPLICATION INFORMATION:

### ● Input Capacitor Selection

Like any low-dropout regulator, the external capacitors used with the LW57XX Series must be carefully selected for regulator stability and performance. Using a capacitor whose value is  $\geq 1\mu\text{F}$  on the LW57XX Series input and the amount of capacitance can be increased without limit. An at least  $10\mu\text{F}$  input capacitor is needed if input ripple voltage  $V_{\text{pp}} > 1\text{V}$ . The input capacitor must be located a distance less than 0.5 inch from the input pin of the IC and returned to a clean analog ground. Any good quality ceramic or tantalum can be used for this capacitor. The capacitor with larger value and lower ESR (equivalent series resistance) provides better PSRR and line-transient response.

### ● Layout considerations

To improve ac performance such as PSRR, output noise, and transient response, it is recommended that the PCB be designed with separate ground planes for VIN and VOUT, with each ground plane connected only at the GND pin of the device.

### ● Output Capacitor Selection

The output capacitor must meet both requirements for minimum amount of capacitance and ESR in all LDOs application. The LW57XX Series is designed specifically to work with low ESR ceramic output capacitor in space-saving and performance consideration. Using a ceramic capacitor whose value is at least  $1\mu\text{F}$  on the LW57XX Series output ensures stability. An appropriate output capacitor can reduce noise and improve load transient response and PSRR. The output capacitor should be located not more than 0.5 inch from the VOUT pin of the LW57XX Series and returned to a clean analog ground.



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Ultra-Low Noise, Fast-Start  
500mA LDO for RF and Analog Circuits

## ORDER INFORMATION:

LW57①②③④⑤⑥

Designator	Item	Symbol	Description
①②	Output Voltage	12~50	e.g. 1.2V → ①=1, ②=2
③④⑤⑥	Packages	A23E	SOT23-5L
		N11E	DFN1x1-4L
		N22G	DFN2x2-6L

Part #	Output Voltage	Package	Shipping
LW5712A23E	1.2V	SOT23-5L	3000 Pcs/ Tape & Reel
LW5715A23E	1.5V		
LW5718A23E	1.8V		
LW5725A23E	2.5V		
LW5728A23E	2.8V		
LW5730A23E	3.0V		
LW5733A23E	3.3V		
LW5736A23E	3.6V		
LW5742A23E	4.2V		
LW5750A23E	5.0V		
LW5712N11E	1.2V	DFN1x1-4L	10000 Pcs/ Tape & Reel
LW5715N11E	1.5V		
LW5718N11E	1.8V		
LW5725N11E	2.5V		
LW5728N11E	2.8V		
LW5730N11E	3.0V		
LW5733N11E	3.3V		
LW5736N11E	3.6V		
LW5742N11E	4.2V		
LW5750N11E	5.0V		

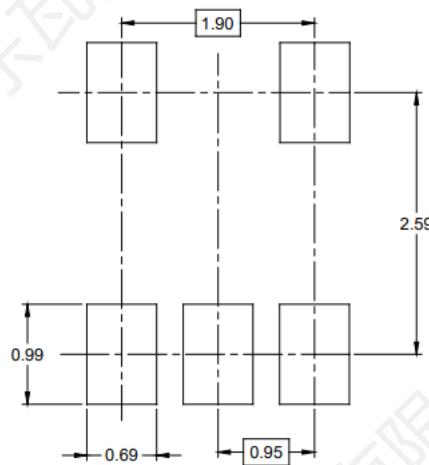
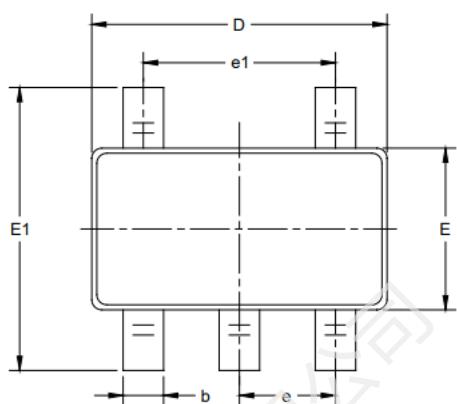


## LW57XX Series

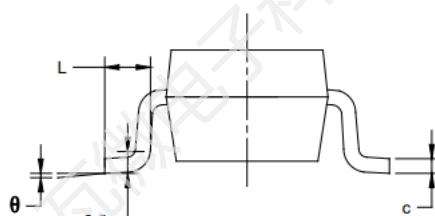
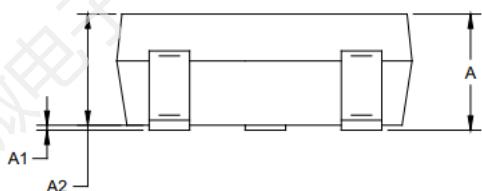
Ultra-Low Noise, Fast-Start  
500mA LDO for RF and Analog Circuits

Part #	Output Voltage	Package	Shipping
LW5712N22G	1.2V	DFN2x2-6L	3000 Pcs/ Tape & Reel
LW5715N22G	1.5V		
LW5718N22G	1.8V		
LW5725N22G	2.5V		
LW5728N22G	2.8V		
LW5730N22G	3.0V		
LW5733N22G	3.3V		
LW5736N22G	3.6V		
LW5742N22G	4.2V		
LW5750N22G	5.0V		

If customers have special output voltage requirements, please contact us.

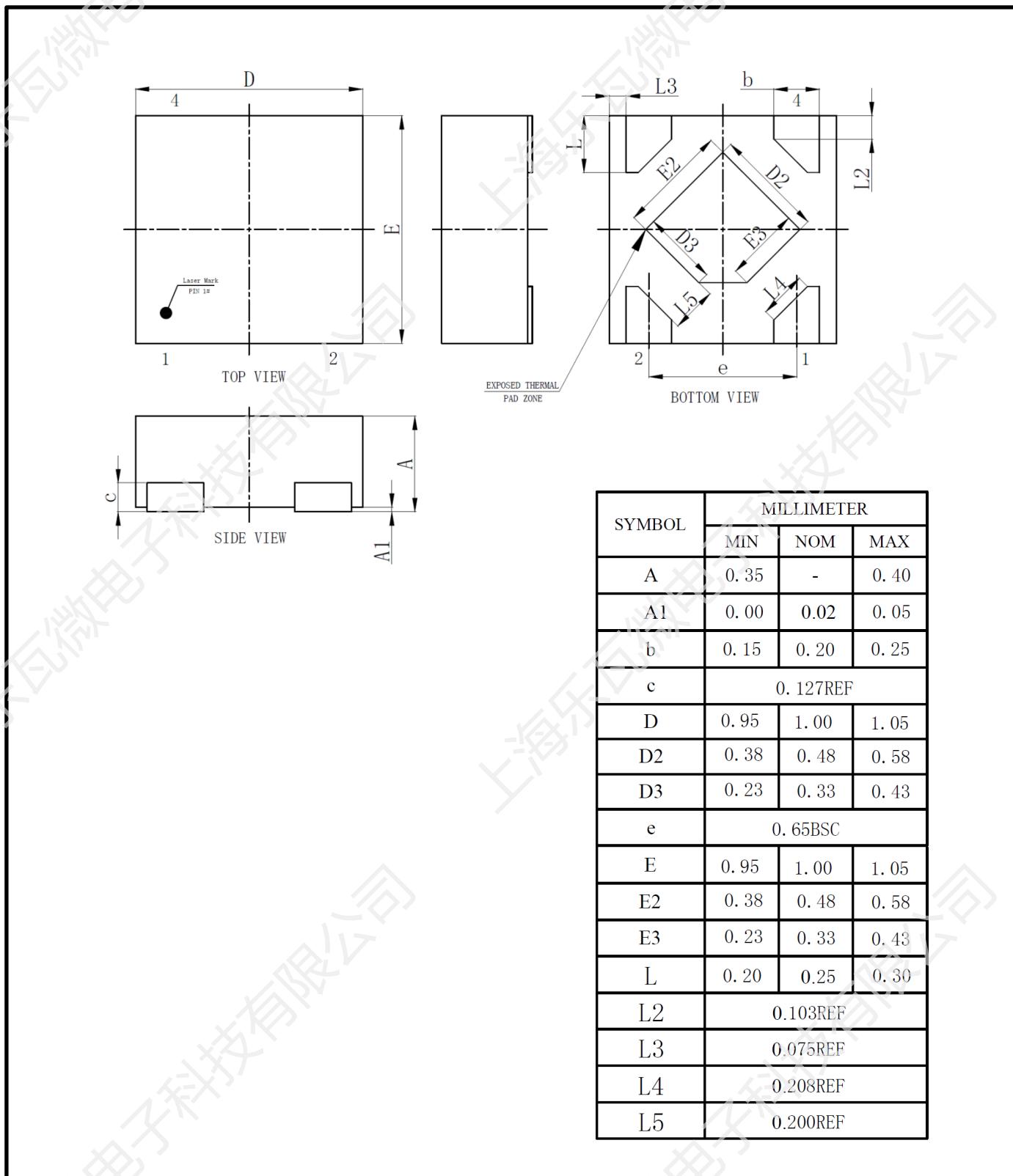
**PACKAGE OUTLINE:**
**SOT23-5L Package**


RECOMMENDED LAND PATTERN (Unit: mm)

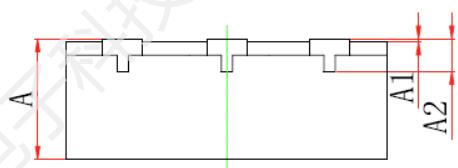
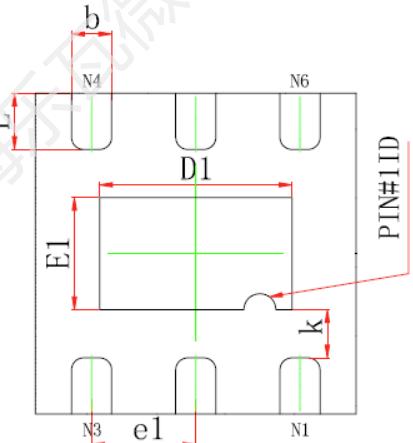
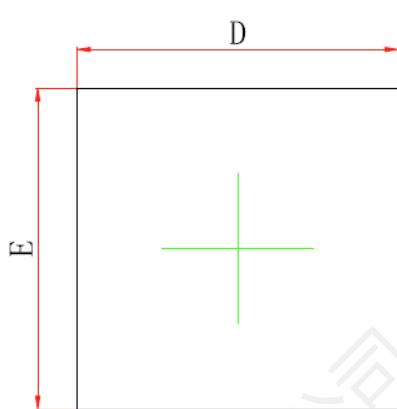


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.320	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950 BSC		0.037 BSC	
e1	1.900 BSC		0.075 BSC	
L	0.300	0.600	0.012	0.024
$\theta$	0°	8°	0°	8°

## DFN1x1-4L Package



## DFN2x2-6L Package



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A2	0.203REF.		0.008REF.	
D	1.924	2.076	0.076	0.082
E	1.924	2.076	0.076	0.082
D1	1.150	1.250	0.045	0.049
E1	0.650	0.750	0.026	0.030
b	0.200	0.300	0.008	0.012
e1	0.650TYP.		0.026TYP.	
k	0.200MIN.		0.008MIN.	
L	0.300	0.400	0.012	0.016



# LW57XX Series

Ultra-Low Noise, Fast-Start  
500mA LDO for RF and Analog Circuits

## Revision History:

Revision	Date	Descriptions
Rev 1.0	Nov.2023	Released Version



## LW57XX Series

Ultra-Low Noise, Fast-Start  
500mA LDO for RF and Analog Circuits

### **DISCLAIMER:**

The information in this document is believed to be accurate and reliable. However, no responsibility is assumed by LW-Micro for its use. All operating parameters must be designed, validated and tested to ensure they meet the requirements of your application. LW-Micro reserves the right to make any specification and/or circuitry changes without prior notification. Before starting a brand-new project, please contact LW-Micro Sales to get the most recent relevant information.

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